



# ACT4515 High Performance 5V/1.2A Car Charger With USB Application Report

## High Performance Car Charger with EMI Solution

### FEATURES

- Wide input voltage range from 10V to 24V
- 5% output voltage accuracy
- No load standby input current 5mA
- 7.5% constant current accuracy
- Thermal shutdown protection
- Cycle-by-cycle current limit
- Cord compensation
- Over current protection with frequency fold back

### SPECIFICATION

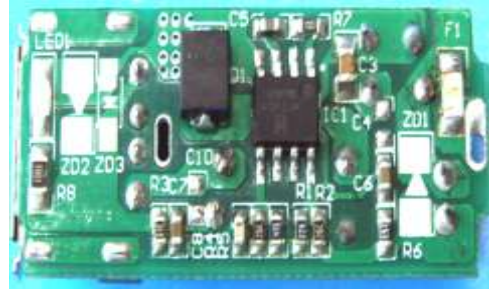
DESCRIPTION	CONDITION	MIN	TYP	MAX	UNITS
Input Voltage		10		24	V
Switching Frequency			210		kHz
No-load Standby Input current	Vin=12V no Load		5		mA
	Vin=24V no Load		4		mA
Output Voltage		4.75	5	5.25	V
Output Current				1200	mA
Ripple Voltage	Vin=12V Io=1.2A		40		mVpp
Efficiency at full load	Vin=12V Io=1.2A		86.3		%
<b>ENVIRONMENTAL</b>					
ESD	Contact		4		kV
	Through air		8		kV
Ambient Temperature	Free convection	0		50	°C

---

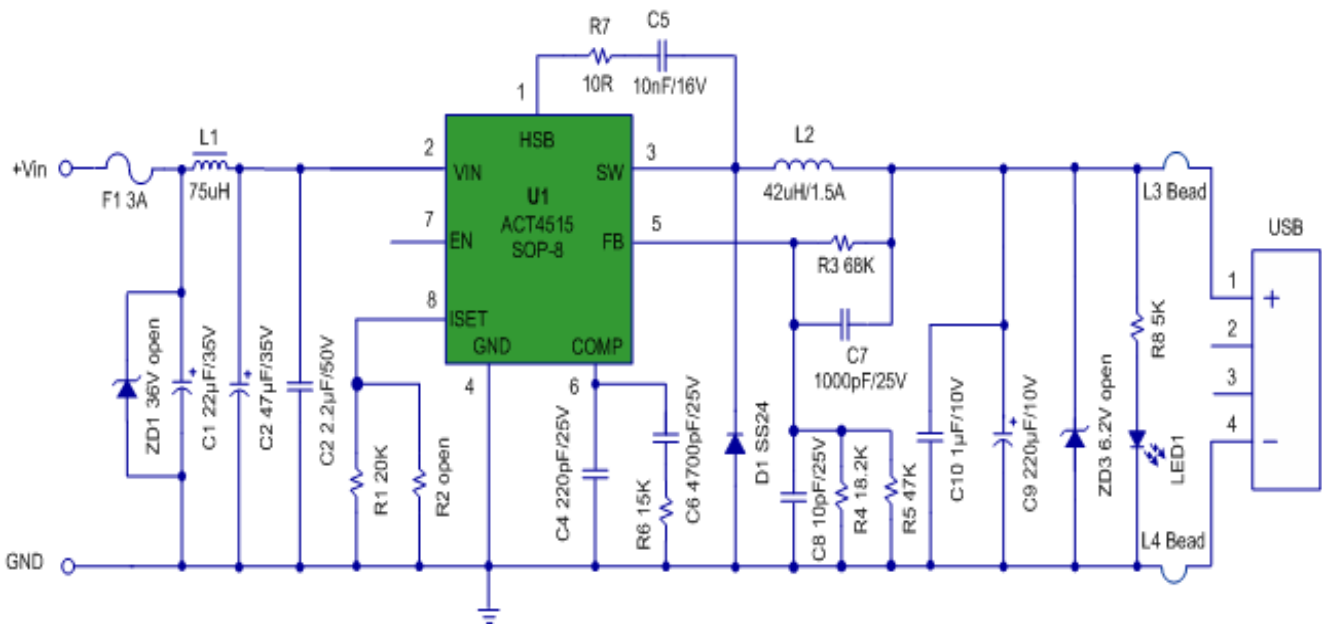
**TABLE OF CONTENTS**

1. Demo Board Photo .....	3
2. Schematics .....	3
3. PCB Layout .....	3
4. Bill of Materials .....	4
5. Functional Test .....	5
5.1. Output Regulation .....	5
5.2. Efficiency .....	5
5.3. Constant Current and Constant Voltage .....	5
5.4. Power Loss .....	6
5.5. Standby Power Loss .....	7
5.6. Switching Frequency, Ripple and Noise .....	7
5.7. Key Components Temperature Test .....	8
6. EMC TEST .....	9
6.1. Conducted EMI Test .....	7
6.2. Radiated EMI Test .....	10
6.3. ESD Test .....	12

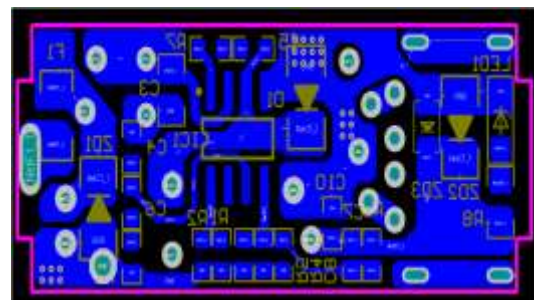
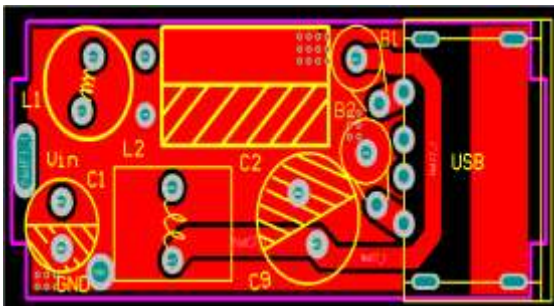
## 1. DEMO BOARD PHOTO



## 2. SCHEMATICS



## 3. PCB LAYOUT



## 4. BILL OF MATERIALS

Item	Reference	Description	QTY	Manufacturer
1	F1	Fuse 3A,1206	1	
2	L1	Choke Coil,75uH,DR=6x8mm, 1A, dip	1	
3	L2	Choke Coil, ring core,42uH,8*4*4mm, 1.5A, dip	1	
	L3,L4	Bead,K5B,T3.5x3x1.2mm		
4	D1	Schottky Diode, SS24/40V, 2A,		Panjit
5	ZD1	Open		
6	ZD2	Open		
7	ZD3	Open		
8	C1	Capacitor,Electrolytic,22uF/35V,Φ5x7mm,Dip	1	KSC
9	C2	Capacitor,Electrolytic,47uF/35V,Φ7.5x8mm,Dip	1	Koshin
10	C3	Ceramic capacitor, 2.2uF/50V, X7R, 0805	1	Murata/TDK
11	C4	Ceramic capacitor, 220pF/25V, X7R, 0603	1	Murata/TDK
12	C5	Ceramic capacitor, 10nF/16V, X7R, 0603	1	Murata/TDK
13	C6	Ceramic capacitor, 4700pF/25V, X7R, 0603	1	Murata/TDK
14	C7	Ceramic capacitor, 1000pF/25V, X7R, 0603	1	Murata/TDK
15	C8	Ceramic capacitor, 10pF/25, X7R, 0603	1	Murata/TDK
16	C9	Capacitor,Electrolytic,220uF/10V,Φ6.3x7.2mm,Dip	1	Micon
17	C10	Ceramic capacitor, 1uF/10V, X7R, 0603	1	Murata/TDK
18	R1	Chip Resistor, 20K Ω , 1/16W, 1%, 0603	1	Murata/TDK
19	R2	Open		
20	R3	Chip Resistor, 68K Ω , 1/16W, 1%, 0603	1	Murata/TDK
21	R4	Chip Resistor, 18.2K Ω , 1/16W, 1%, 0603	1	Murata/TDK
22	R5	Chip Resistor, 47K Ω , 1/16W, 1%, 0603	1	Murata/TDK
23	R6	Chip Resistor, 15K Ω , 1/16W ,5%, 0603	1	Murata/TDK
24	R7	Chip Resistor, 10 Ω , 1/16W, 5%,0603	1	Murata/TDK
25	R8	Chip Resistor, 5K Ω , 1/16W, 5%,0805	1	Murata/TDK
26	U1	IC, ACT4515 SO-8	1	Active semi
27	LED	LED ,Green,0805	1	LED Manu
28	USB	15mm*10mm*8mm	1	USB Manu

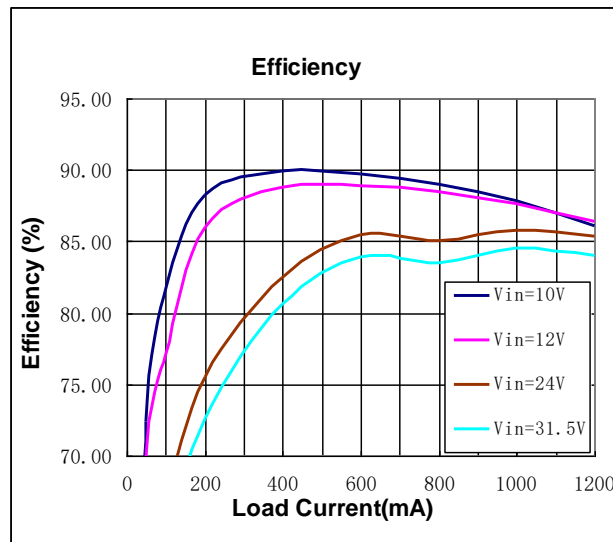
## 5. FUNCTIONAL TEST

### 5.1. Output Regulation

Voltage	Output Voltage at Max. load	Output Voltage at Min. load	Load regulation	Iload(max)
Vin=24V	5.08	4.97	-2.2%	1.2A
Vin=12V	5.09	4.98	-2.2%	

### 5.2. Efficiency

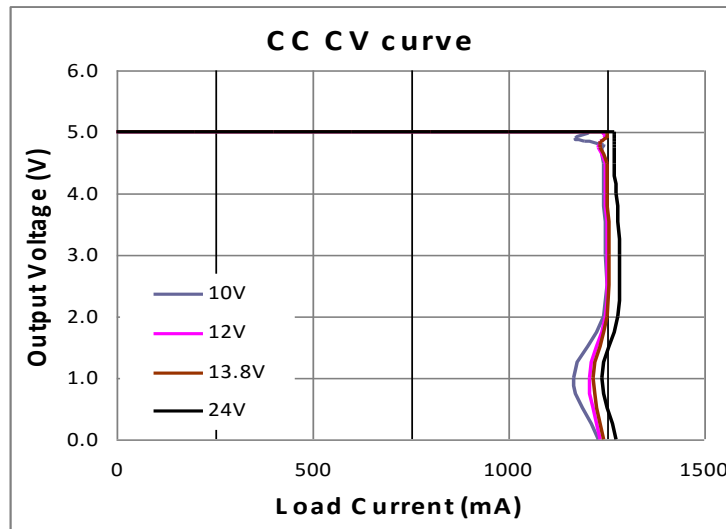
Iout	Efficiency (%)							
	Io=0mA	Io=100mA	Io=200mA	Io=400mA	Io=600mA	Io=800mA	Io=1000mA	Io=1200mA
Vin=31.5V	0.00	63.40	72.56	80.58	83.91	83.50	84.49	84.06
Vin=24V	0.00	66.50	75.54	82.44	85.44	85.08	85.81	85.31
Vin=12V	0.00	76.93	85.96	88.80	88.84	88.49	87.68	86.36
Vin=10V	0.00	81.48	88.23	89.88	89.66	88.96	87.89	86.11



### 5.3. Constant Current and Constant Voltage

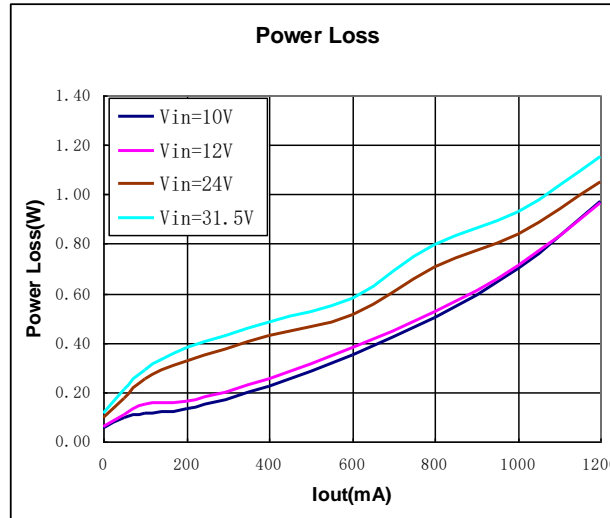
	Vin=24V	Vin=24V	Vin=13.8V	Vin=13.8V	Vin=12V	Vin=12V	Vin=10V	Vin=10V
	Vout	Iout (mA)	Vout	Iout (mA)	Vout	Iout (mA)	Vout	Iout (mA)
CC load	5	0	5	0	5	0	5	0
	5	200	5	200	5	200	5	200
	5	400	5	400	5	400	5	400
	5	600	5	600	5	600	5	600
	5	800	5	800	5	800	5	800
	5	1000	5	1000	5	1000	5	1000
	5	1270	5	1250	5	1240	5	1200

<b>CV load</b>	4.95	1270	4.95	1250	4.95	1245	4.95	1180
	4.9	1270	4.9	1250	4.9	1246	4.9	1171
	4.85	1270	4.85	1233	4.85	1232	4.85	1192
	4.8	1270	4.8	1234	4.8	1233	4.8	1241
	4.75	1270	4.75	1233	4.75	1229	4.75	1240
	4.5	1270	4.5	1251	4.5	1246	4.5	1242
	4	1274	4	1254	4	1248	4	1244
	3	1284	3	1259	3	1253	3	1247
	2	1278	2	1254	2	1248	2	1243
	1	1238	1	1216	1	1209	1	1166
	0	1273	0	1244	0	1236	0	1230



#### 5.4. Power Loss

VIN	Power loss (W)							
	Io=0mA	Io=100mA	Io=200mA	Io=400mA	Io=600mA	Io=800mA	Io=1000mA	Io=1200mA
Vin=31.5V	0.12	0.29	0.38	0.48	0.58	0.80	0.93	1.15
Vin=24V	0.09	0.25	0.32	0.43	0.51	0.71	0.84	1.05
Vin=12V	0.06	0.15	0.16	0.25	0.38	0.53	0.71	0.97
Vin=10V	0.05	0.11	0.13	0.23	0.35	0.50	0.70	0.97



### 5.5. Standby Power Loss

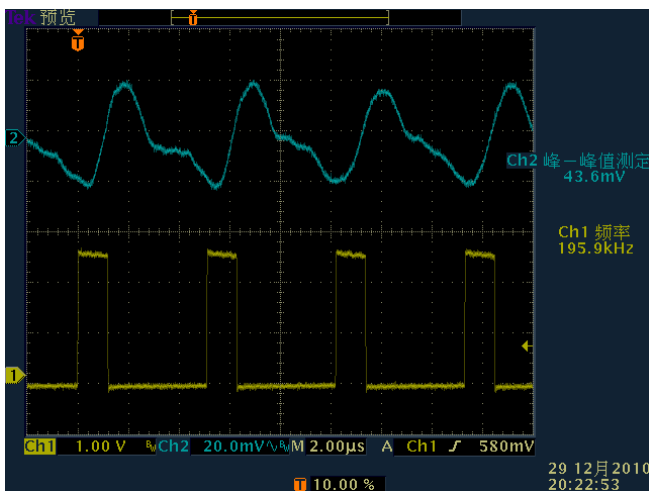
Test Conditions	Iin at No Load	Power Loss at No Load	
Vin=24V	4mA	90mW	Max Load: 1.2A No Load: 0A
Vin=12V	5mA	60mW	

### 5.6. Switching Frequency, Ripple and Noise

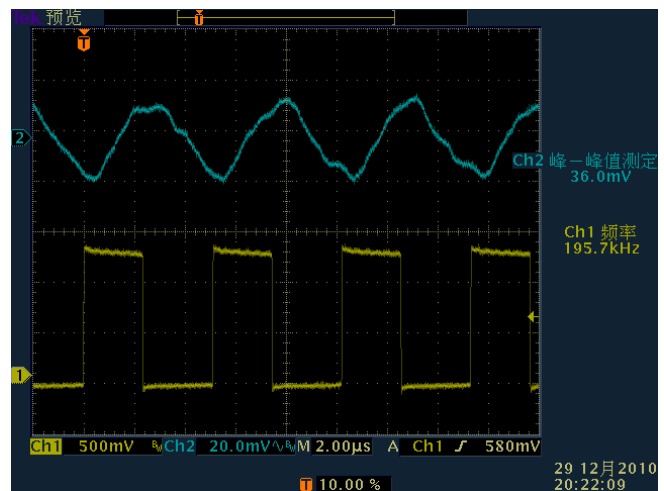
Ripple & noise are measured by using 20MHz bandwidth limited oscilloscope.

Test Conditions	Max load (mV)	Mini Load(mV)	
Vin=24V	45	13	Max Load: 1A Mini Load: 0mA
Vin=12V	36	14	

Vin=24V Io=1.2A



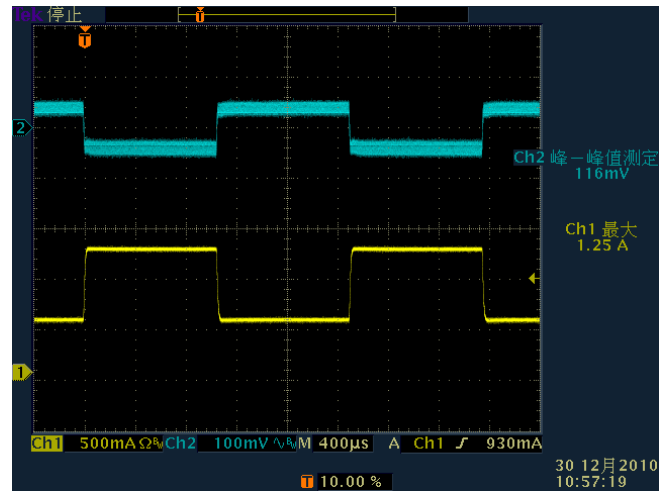
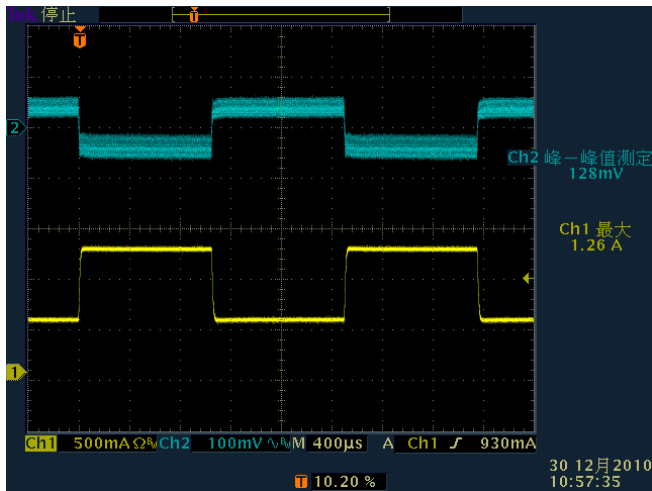
Vin=12V Io=1.2A



### 5.7. Dynamic Response

Vin=24V load step from 40%-100%

Vin=12V load step from 40%-100%



### 5.8. Key Components Temperature Test

Test condition: Ambient Temp: 60 °C; full load I<sub>o</sub>=1200mA

Test on IC, Inductor, diode, C<sub>in</sub>, C<sub>out</sub> and PCB. Burning for 2 hours

Test Conditions	IC (°C)	Inductor(°C)	Diode(°C)	C <sub>in</sub> (°C)	C <sub>out</sub> (°C)	PCB(°C)
Vin=24V	114.7	125.3	109	96	98.1	98.4
Vin=12V	113	115.7	104	94.5	94.9	95.1



## 6. EMC TEST

### 6.1. Conducted EMI Test

Vin=24V Io=1A

### EMI TEST REPORT

Organization: ACT  
 Place: ACT LAB  
 Detector: PK+AV  
 Limit: EN55022  
 Remark: ACT4515 5V1.2A L

Operator:  
 Time: 2010/12/30/16:50  
 Test-time(ms): 5  
 Transductor: 1

EUT:

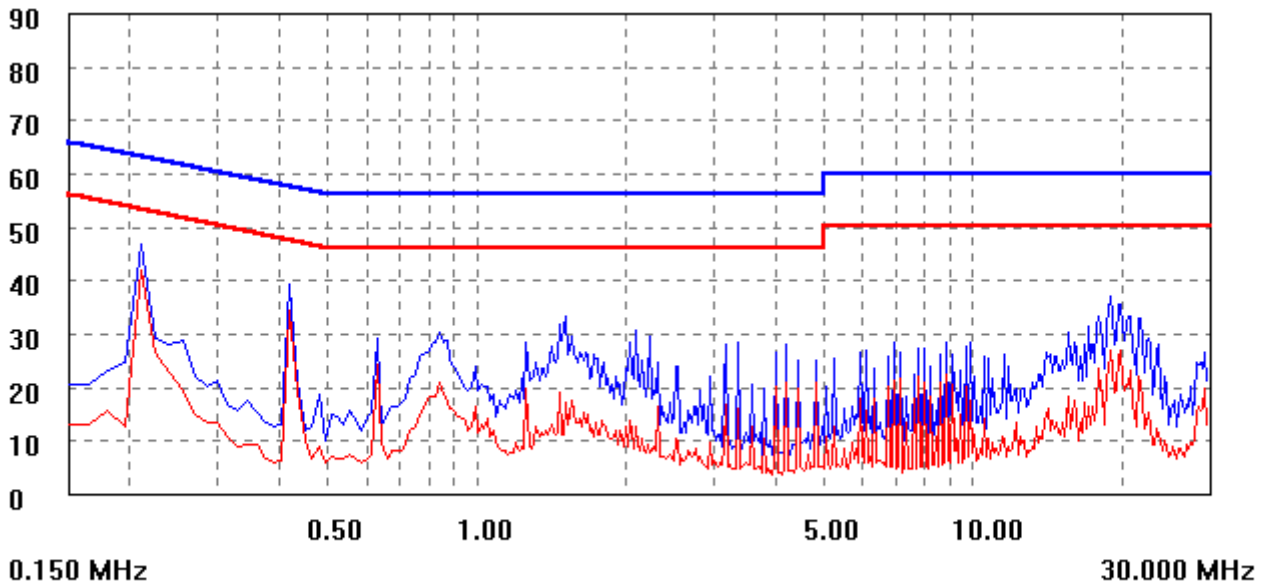
parameter

Start(MHz)	End(MHz)	Step(MHz)
0.150	5.000	0.015
5.000	30.000	0.030

freq, step

dBuV

scan result



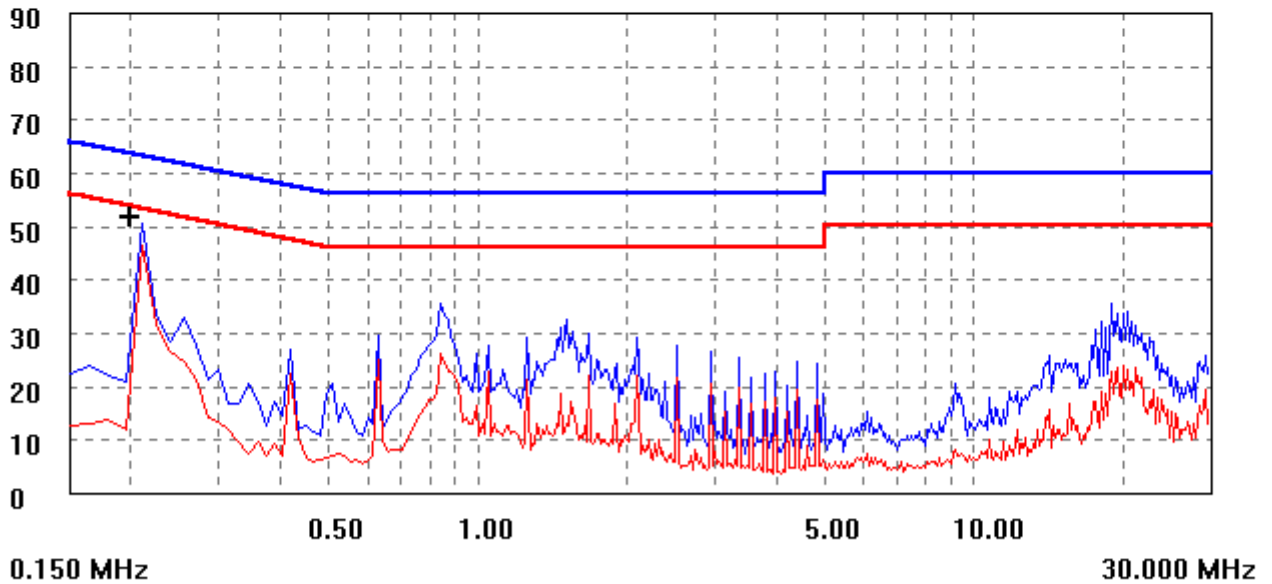
Vin=12V Io=1A

## EMI TEST REPORT

<b>Organization:</b> ACT	<b>Operator:</b>	<b>EUT:</b>
<b>Place:</b> ACT LAB	<b>Time:</b> 2010/12/30/16:48	
<b>Detector:</b> PK+AV	<b>Test-time(ms):</b> 5	
<b>Limit:</b> EN55022	<b>Transducer:</b> 1	
<b>Remark:</b> ACT4515 5V1.2A L		

<b>Start(MHz)</b>	<b>End(MHz)</b>	<b>Step(MHz)</b>
0.150	5.000	0.015
5.000	30.000	0.030

**dBuV**



**final test**

## 6.2. Radiated EMI Test

Vin=12V Io=1A H



**ACCURATE TECHNOLOGY CO., LTD.**

F1,Bldg,A,Changyuan New Material Port Keyuan Rd,  
Science & Industry Park,Nanshan Shenzhen,P.R.China

Site: 966 chamber

Tel:+86-0755-26503290

Fax:+86-0755-26503396

Job No.: ACT #990

Standard: EN55022 ClassB Radiated

Test item: Radiation Test

Temp.( C)/Hum.(%) 25 C / 50 %

EUT:

Mode: FULL LOAD

Model: ACT4515

Manufacturer: ACT

Polarization: Horizontal

Power Source: DC 12V

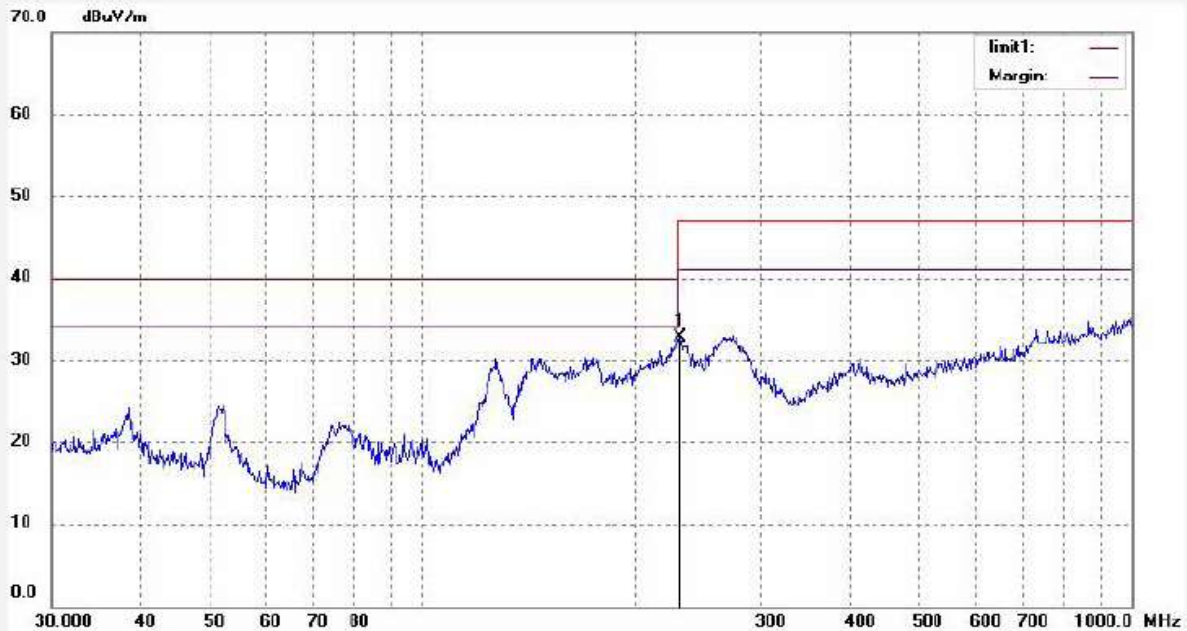
Date: 2011/01/07

Time: 16:05:02

Engineer Signature: MASON

Distance: 3m

Note: 2#



No.	Freq. (MHz)	Reading (dBuV/m)	Factor (dB)	Result (dBuV/m)	Limit (dBuV/m)	Margin (dB)	Detector	Height (cm)	Degree (deg.)	Remark
1	231.0399	15.95	16.84	32.79	47.00	-14.21	peak			

Vin=12V Io=1A V



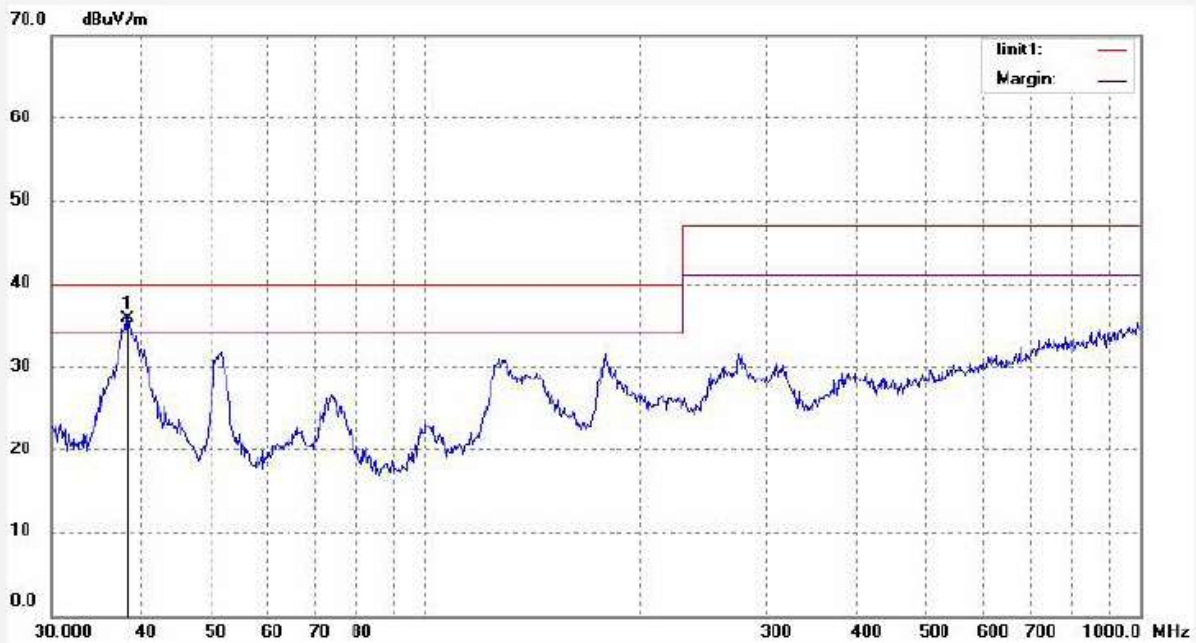
**ACCURATE TECHNOLOGY CO., LTD.**  
 F1,Bldg,A,Changyuan New Material Port Keyuan Rd,  
 Science & Industry Park,Nanshan Shenzhen,P.R.China

Site: 966 chamber  
 Tel:+86-0755-26503290  
 Fax:+86-0755-26503396

Job No.: ACT #989  
 Standard: EN55022 ClassB Radiated  
 Test item: Radiation Test  
 Temp.( C)/Hum.(%) 25 C / 50 %  
 EUT:  
 Mode: FULL LOAD  
 Model: ACT4515  
 Manufacturer: ACT

Polarization: Vertical  
 Power Source: DC 12V  
 Date: 2011/01/07  
 Time: 16:03:49  
 Engineer Signature: MASON  
 Distance: 3m

Note: 2#



No.	Freq. (MHz)	Reading (dBuV/m)	Factor (dB)	Result (dBuV/m)	Limit (dBuV/m)	Margin (dB)	Detector	Height (cm)	Degree (deg.)	Remark
1	38.3650	19.35	16.46	35.81	40.00	-4.19	peak			

### 6.3. ESD Test

Test Condition	Vin=24V Io=1A	Vin=12V Io=1A
4KV contact	30 times pass	30 times pass
8KV air	30 times pass	30 times pass